



SCT5450

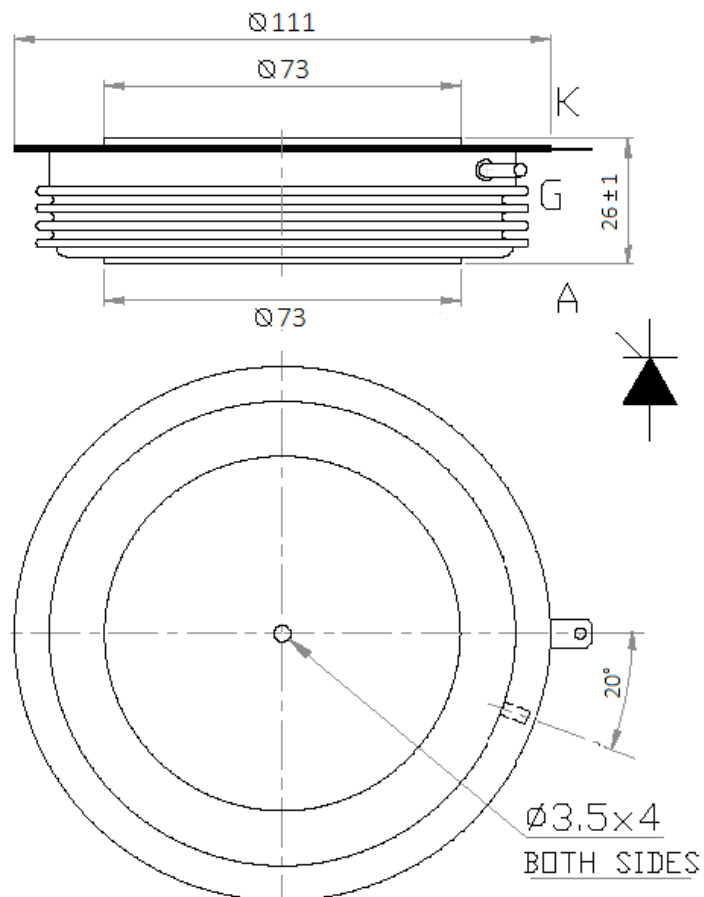
Power Rectifier Thyristor

Key Parameters

V_{DRM} / V_{RRM}	= 800V
$I_{T(AV)}$	= 5450A
I_{TSM}	= 74kA
$V_{T(TO)}$	= 0.84V
r_T	= 0.06mΩ

Features

- Full blocking capability over wide temperature range
- High Surge current capability
- Hermetic metal case with ceramic insulator



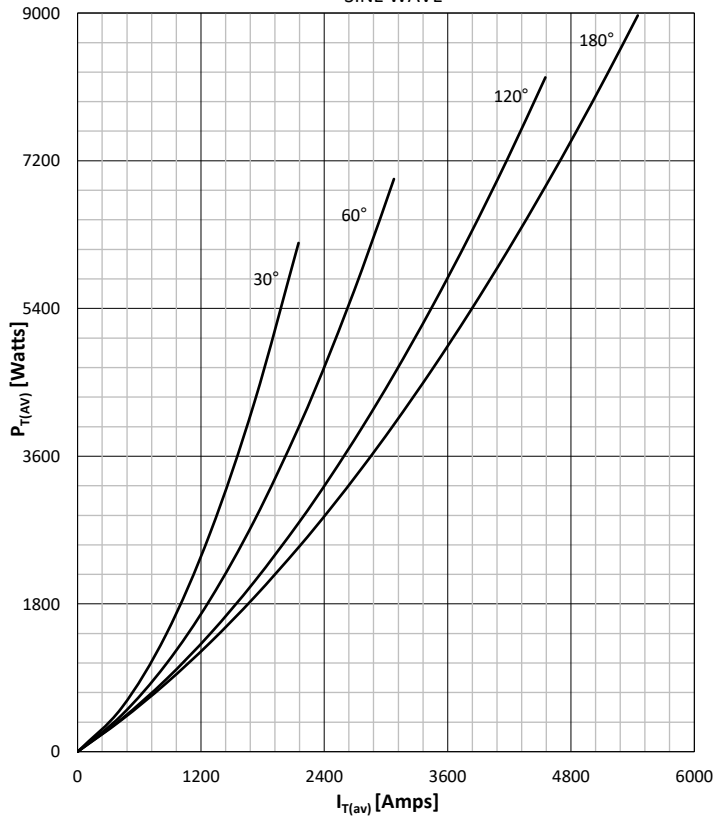
Applications

- Battery Chargers
- Medical Equipment
- UPS
- Power Supplies
- Motor control
- Controlled Rectifiers
- Transportation
- Induction Heating
- Welding

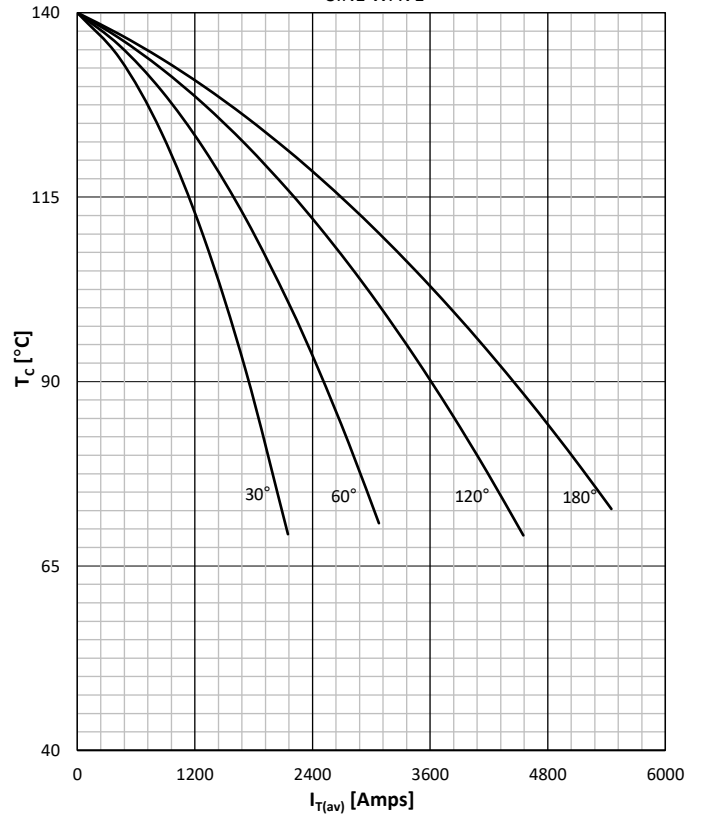
Symbol	Characteristic	Conditions	T _j [°C]	Value	Unit
BLOCKING					
V _{RRM}	Repetitive peak reverse voltage		140	200 - 800	V
V _{RSM}	Non-repetitive peak reverse voltage		140	300 - 900	V
V _{DRM}	Repetitive peak off-state voltage		140	200 - 800	V
I _{RRM}	Repetitive peak reverse current	V = V _{RRM}	140	200	mA
I _{DRM}	Repetitive peak off-state current	V = V _{DRM}	140	200	mA
CONDUCTING					
I _{T(AV)}	Mean on state current	180° sin ,50 Hz, T _c =73°C, Double side cooled		5450	A
I _{RMS}	RMS on-state current			8556	A
I _{TSM}	Surge on-state current	Sine wave, 10 ms Without reverse voltage	25	74000	A
			140	70000	A
I ² t	I ² t	Sine wave, 10 ms Without reverse voltage	25	27380 x 10 ³	A ² s
			140	24500 x 10 ³	A ² s
V _T	On-state voltage	On-state current = 2000A	140	0.96	V
V _{T(TO)}	Threshold voltage		140	0.84	V
r _T	On-state slope resistance		140	0.06	mΩ
SWITCHING					
di/dt	Critical rate of rise of on-state current		140	320	A/μs
dv/dt	Critical rate of rise of off-state voltage	V _{DR} = 67%V _{DRM}	140	500	V/μs
GATE					
I _{gt}	Gate trigger current	V _D =6V	25	300	mA
V _{gt}	Gate trigger voltage	V _D =6V	25	3.0	V
I _H	Holding current	V _D =6V, gate open circuit	25	400	mA
I _L	Latching current	V _D =6V	25	1000	mA
MOUNTING					
R _{th(j-c)}	Thermal impedance, sin 180°	Junction to case, Double side cooled		0.0075	°C/W
R _{th(j-c)}	Thermal impedance, rec120°	Junction to case, Double side cooled		0.0086	°C/W
R _{th(c-h)}	Thermal impedance	Case to heatsink, Double side cooled		0.002	°C/W
T _j	Max. junction temperature			140	°C
T _{stg}	Storage temperature			-40 140	°C
M	Clamping Force			40 - 50	kN
W	Weight (Approx.)			1200	gm

DISSIPATION CHARACTERISTICS

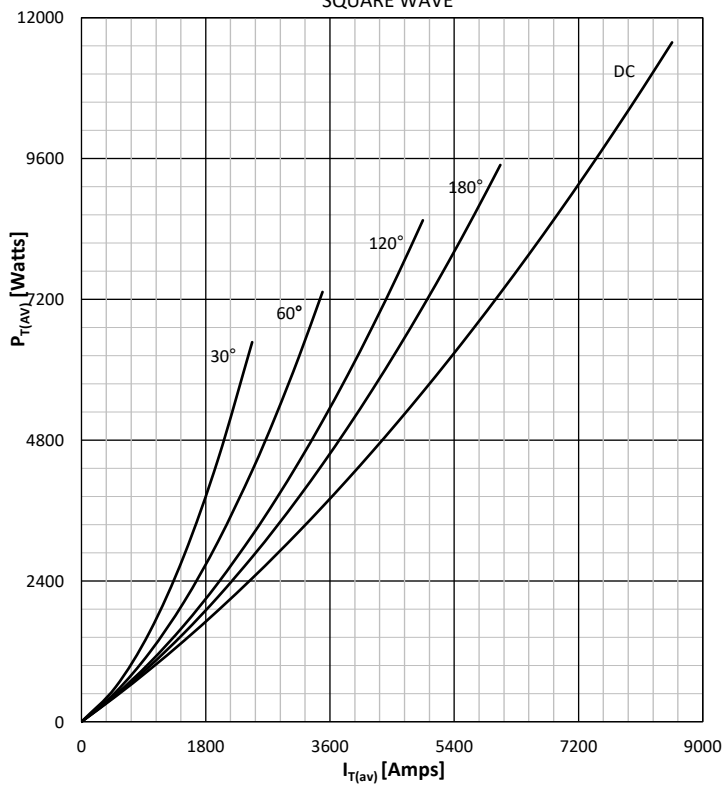
SINE WAVE


ON STATE CURRENT DERATING CURVE

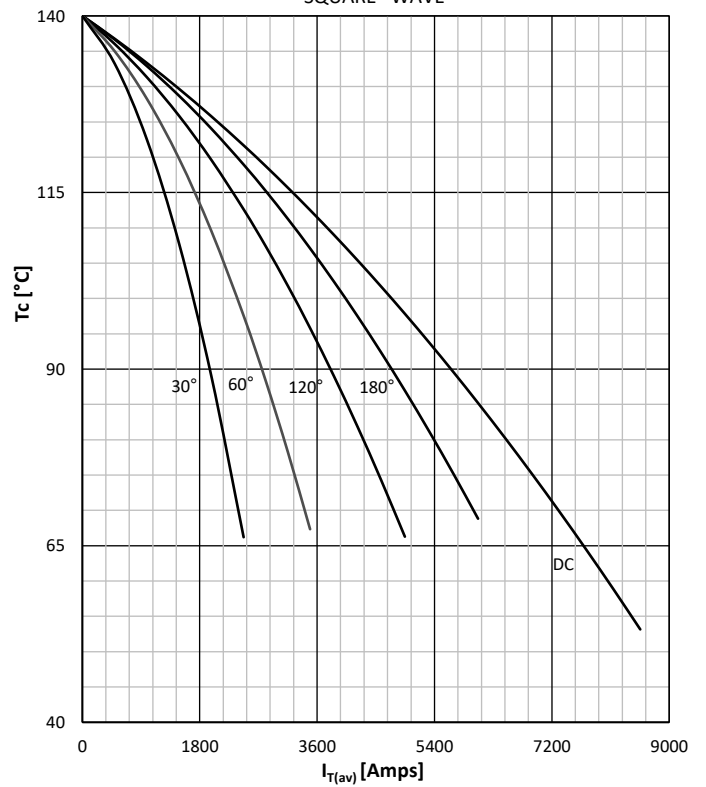
SINE WAVE

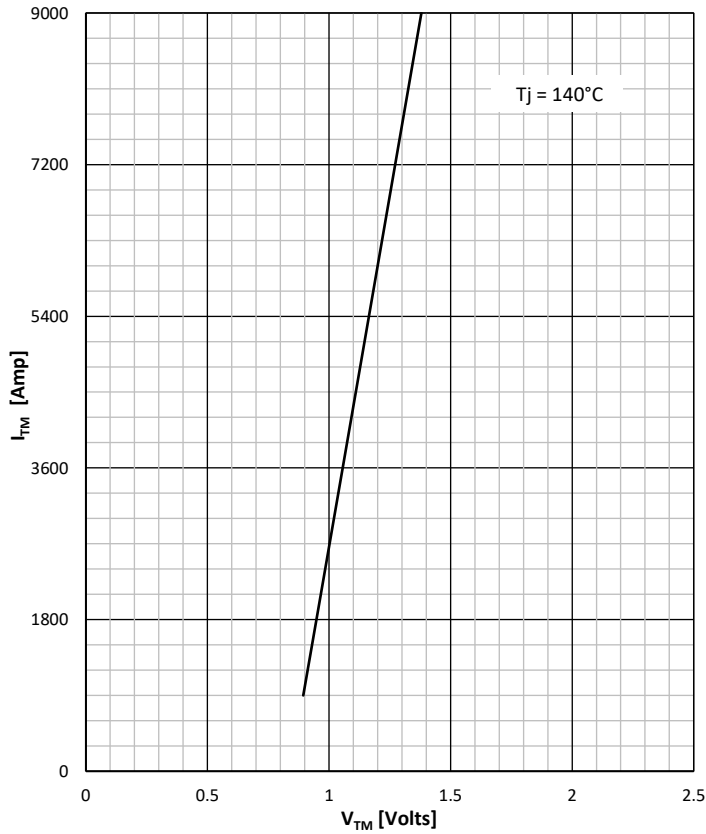
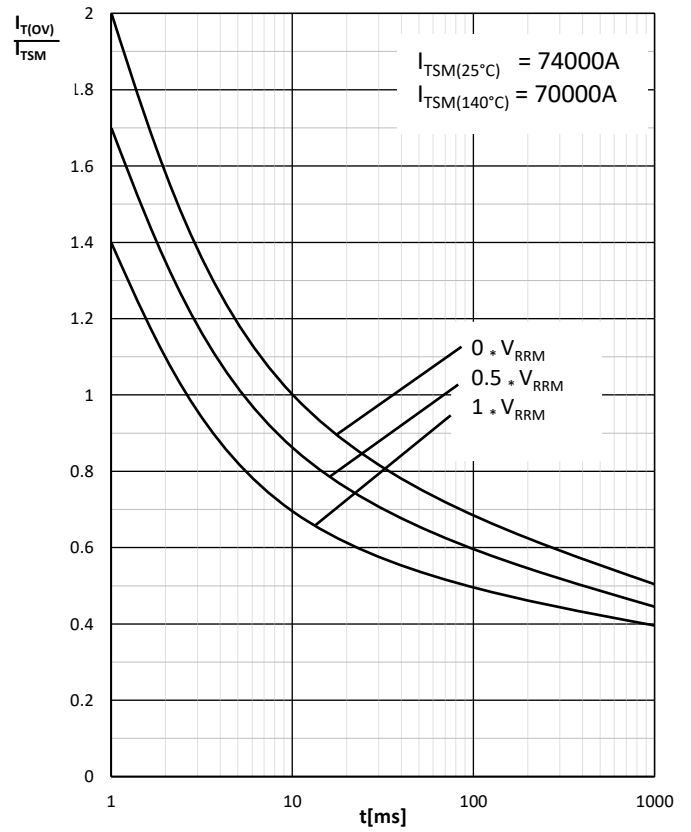
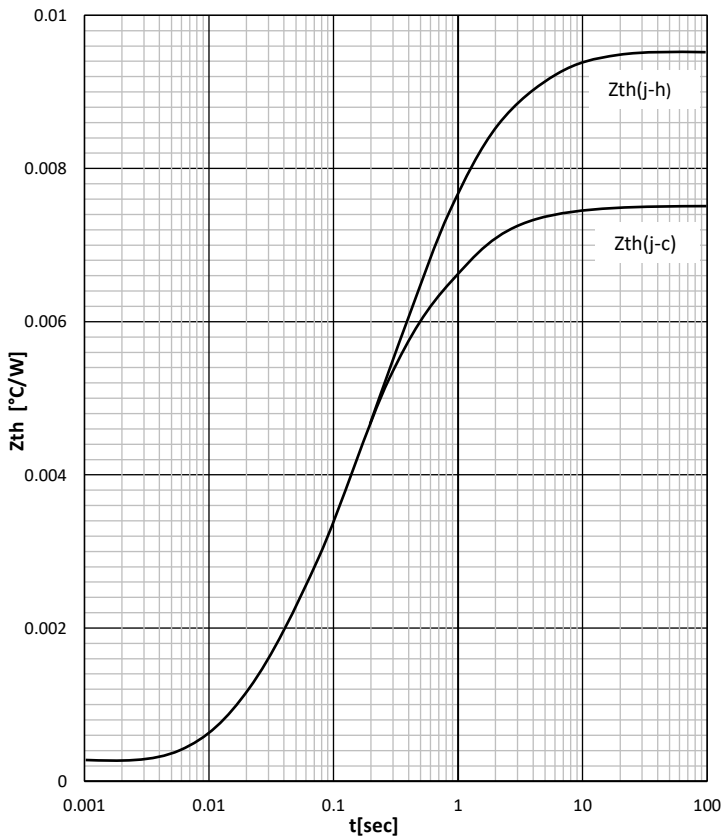

DISSIPATION CHARACTERISTICS

SQUARE WAVE


ON STATE CURRENT DERATING CURVE

SQUARE WAVE



ON STATE CHARACTERISTIC

SURGE CHARACTERISTICS

TRANSIENT THERMAL IMPEDANCE

GATE TRIGGER CHARACTERISTICS
